

P-Channel Enhancement Mode Field Effect Transistor

FEATURES

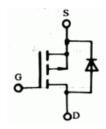
- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- TO-252 package

	PRODUCT S	UMMARY			
	V_{DSS}	ID	$RDS(ON)$ $(m \Omega)$ Typ		
	-30V	15	98@ VGS=-10V		
		-15	130 @ VGS=-4.5V		



NOTE: The MT4435L is available in a lead-free package





ABSOLUTE MAXIUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-30	V
Gate-Source Voltage	VGS	±20	V
Drain Current-Continuous ^a @Tj=125°C	ID	-15	A
- Pulse d^{b}	Ідм	-24	A
Drain-source Diode Forward Current ^a	Is	-1.8	A
Maximum Power Dissipation ^a	PD	50	W
Operating Junction and Storage Temperature Range	TJ,Tstg	-55 to 150	$^{\circ}$

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a	Rth JA	50	°C/W	
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ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
OFF CHARACTERISTICS			•		•		
Drain-Source Breakdown Voltage	BVDSS	V _{GS} =0V,I _D =-250μA	-30			V	
Zero Gate Voltage Drain Current	Idss	VDS=-24V,VGS=0V			-1	μД	
Gate-Body Leakage	Igss	Vgs=±20V,Vds=0V			±100	nA	
ON CHARACTERITICS							
Gate Threshold Voltage	V _G s(th)	Vds=Vgs,Id=-250µA	-1	-1.5	-2.5	V	
Drain-Source On-State Resistance	Process	Vgs=-10V,Id=-12A		38	50	- m Ω	
Drain-Source On-State Resistance	RDS(ON)	Vgs=-4.5V,Id=-5.6A		70	85		
Forward Transconductance	gFS	Vgs=-5V,Id=-12A		5		S	
DAYNAMIC CHARACTERISTICS							
Input Capacitance	Ciss	V _{DS} =-15V,V _{GS} =0V f=1.0MHz		582		pF	
Output Capacitance	Coss			125		pF	
Reverse Transfer Capacitance	Crss			86		pF	
SWITCHING CHARACTERISISTICS							
Turn-On Delay Time	td(ON)	V _{DD} =-15V		9		ns	
Rise Time	tr	ID=-10A,		10		ns	
Turn-Off Delay Time	t _{D(OFF)}	V _{GEN} =-4.5V R _L =10ohm		38		ns	
Fall Time	tf	Rgen=60hm		23		ns	
Total Gate Charge	Q g	Vds=-15V,Id=-1A Vgs=-10V		11.7		nC	
Gate-Source Charge	Qgs			2.1		nC	
Gate-Drain Charge	Qgd			2.9		nC	

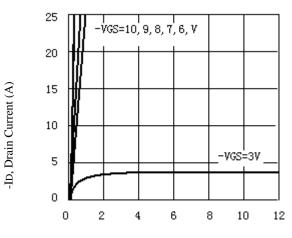


ELECTRICAL CHARACTERICS (TA=25°C unless otherwise noted)

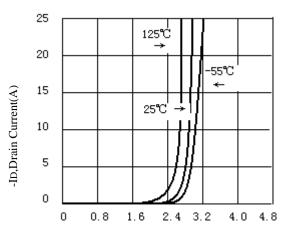
Parameter	Symbol	Condition	Min	Тур	Max	Unit	
DRAIN-SOURCE DIODE CHARACTERISTICS							
Diode Forward Voltage	Vsd	Vgs=0V,Is=-1.7A		-0.84	-1.2	V	

Notes

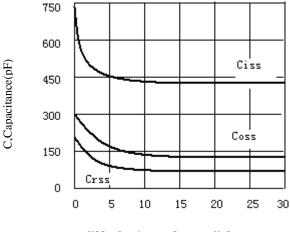
- a. Surface Mounted on FR4 Board, t ≤ 10sec
- b. Pulse Test: Pulse Width ≤ 300 Us, Duty $\leq 2\%$
- c. Guaranteed by design, not subject to production testing.



- VDS, Drain-to-Source Voltage (V) Figure 1. Output Characteristics



-VGS, Gate-to-source Voltage (V) Figure 2. Transfer Characteristics



- VGS, Drain-to Source Voltage Figure 3. Capacitance

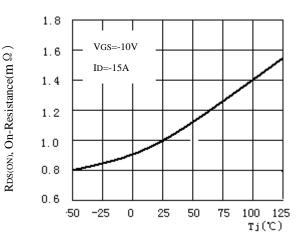
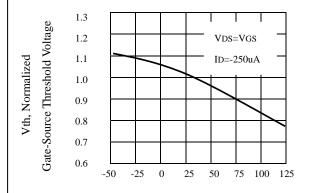
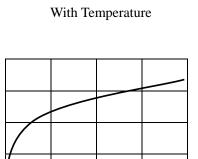


Figure 4. On-Resistance Variation with Temperature



Tj., Junction Temperature ($^{\circ}$ C) Figure 5. Gate Threshold Variation With Temperature



10

8

6

4

2

0

9FS, Transconductance (S)

-VGS, Gate to Source Voltage

-IDS, Drain-Source Current (A)

10

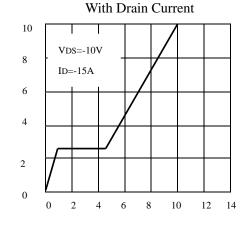
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VGS=-15V

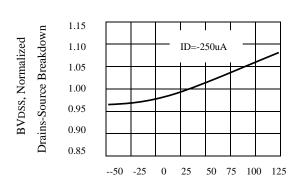
15

20

Figure 7. Transconductance Variation



Qg, Total Gate Charge(nC)
Figure 9. Gate Charge



Tj, Junction Temperature (${}^{\circ}$ C) Figure6.Breakdown Voltage Variation With Temperature

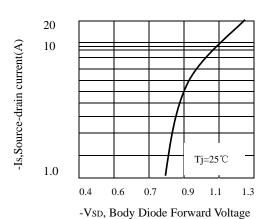
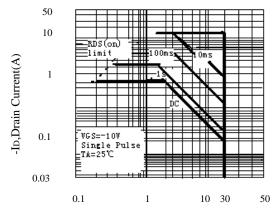


Figure 8. Body Diode Forward Voltage
Variation with Source Current



-VDS, Drain-Source Voltage(V)
Figure 10.Maximum Safe Operating Area

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